

# MPSW13

## One Watt Darlington Transistor

### NPN Silicon

#### Features

- Pb-Free Package is Available\*

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	$V_{CES}$	30	Vdc
Collector – Base Voltage	$V_{CBO}$	30	Vdc
Emitter – Base Voltage	$V_{EBO}$	10	Vdc
Collector Current – Continuous	$I_C$	1.0	Adc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	1.0 8.0	W mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	2.5 20	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

#### THERMAL CHARACTERISTICS

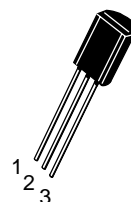
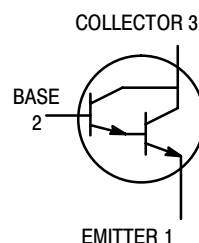
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	$^\circ\text{C/W}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



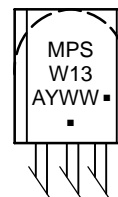
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<http://onsemi.com>



TO-92 (TO-226)  
CASE 29-10  
STYLE 1

#### MARKING DIAGRAM



MPSW13 = Device Code

A = Assembly Location

Y = Year

WW = Work Week

▪ = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

Device	Package	Shipping†
MPSW13RLRA	TO-92	2,000/Tape & Reel
MPSW13RLRAG	TO-92 (Pb-Free)	2,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MPSW13

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector–Emitter Breakdown Voltage ( $I_C = 100\ \mu\text{A}$ , $V_{BE} = 0$ )	$V_{(BR)CES}$	30	–	Vdc
Collector Cutoff Current ( $V_{CB} = 30\ \text{Vdc}$ , $I_E = 0$ )	$I_{CBO}$	–	100	nA
Emitter Cutoff Current ( $V_{EB} = 10\ \text{Vdc}$ , $I_C = 0$ )	$I_{EBO}$	–	100	nA
<b>ON CHARACTERISTICS (Note 1)</b>				
DC Current Gain ( $I_C = 10\ \text{mA}$ , $V_{CE} = 5.0\ \text{Vdc}$ ) ( $I_C = 100\ \text{mA}$ , $V_{CE} = 5.0\ \text{Vdc}$ )	$h_{FE}$	5,000 10,000	– –	–
Collector–Emitter Saturation Voltage ( $I_C = 100\ \text{mA}$ , $I_B = 0.1\ \text{mA}$ )	$V_{CE(sat)}$	–	1.5	Vdc
Base–Emitter On Voltage ( $I_C = 100\ \text{mA}$ , $V_{CE} = 5.0\ \text{Vdc}$ )	$V_{BE(on)}$	–	2.0	Vdc
<b>SMALL–SIGNAL CHARACTERISTICS</b>				
Current–Gain – Bandwidth Product (Note 2) ( $I_C = 10\ \text{mA}$ , $V_{CE} = 5.0\ \text{Vdc}$ , $f = 100\ \text{MHz}$ )	$f_T$	125	–	MHz

1. Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .
2.  $f_T = |h_{fe}| \cdot f_{test}$ .

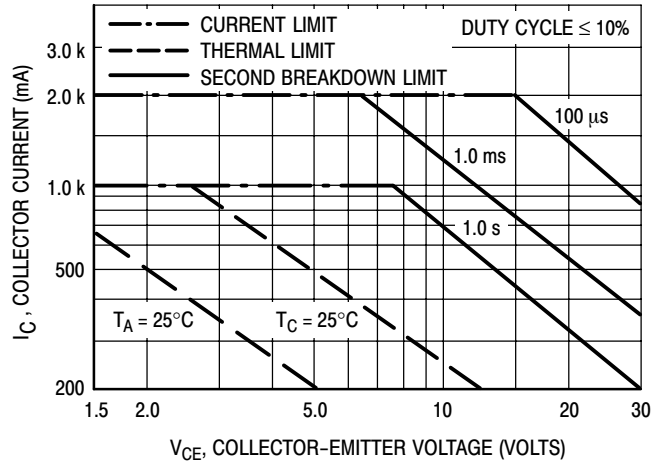


Figure 1. Active Region – Safe Operating Area

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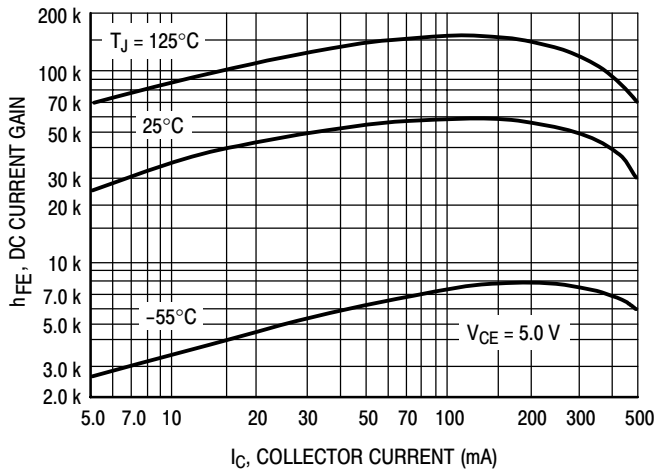


Figure 2. DC Current Gain

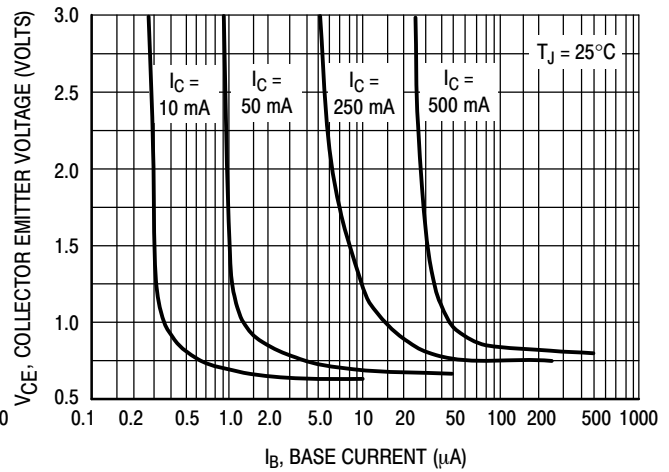


Figure 3. Collector Saturation Region

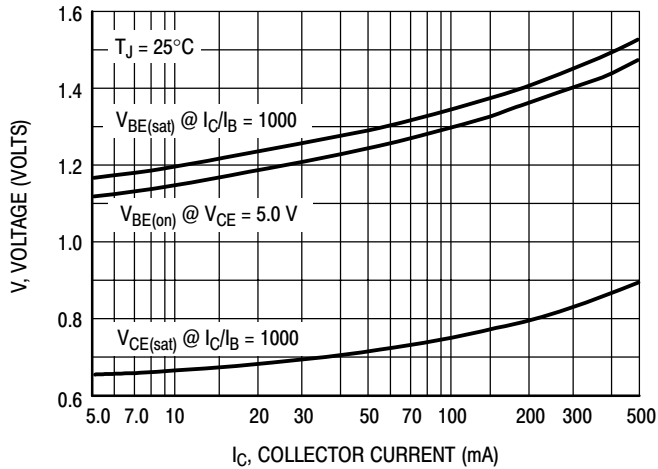


Figure 4. "ON" Voltages

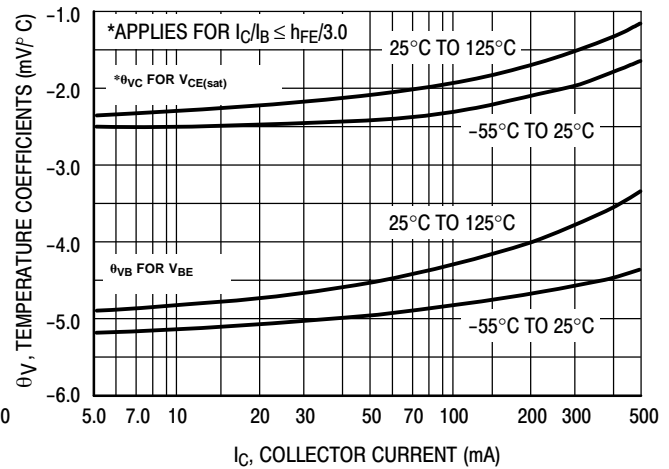


Figure 5. Temperature Coefficients

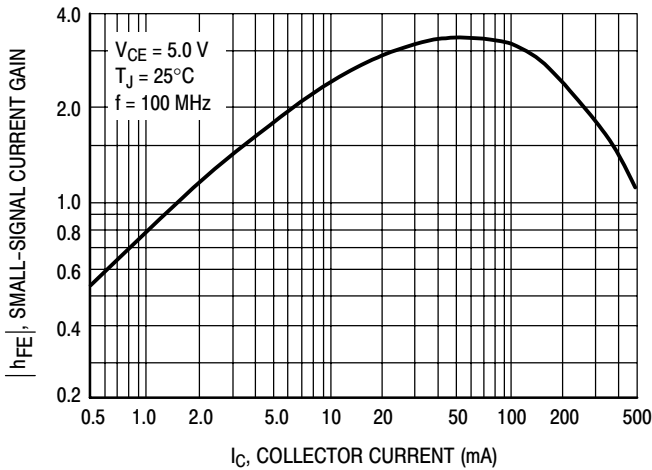


Figure 6. High Frequency Current Gain

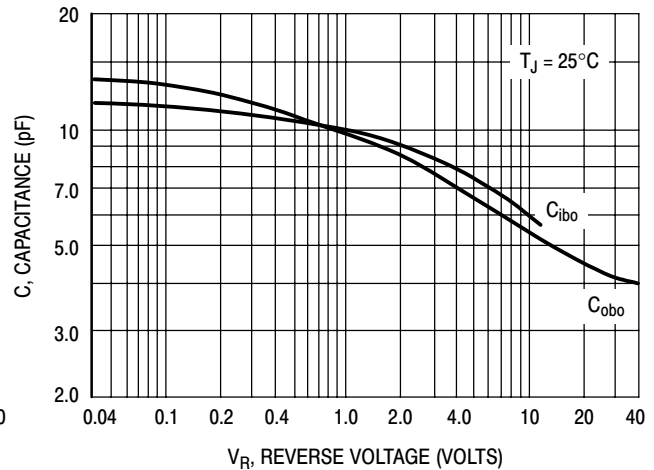
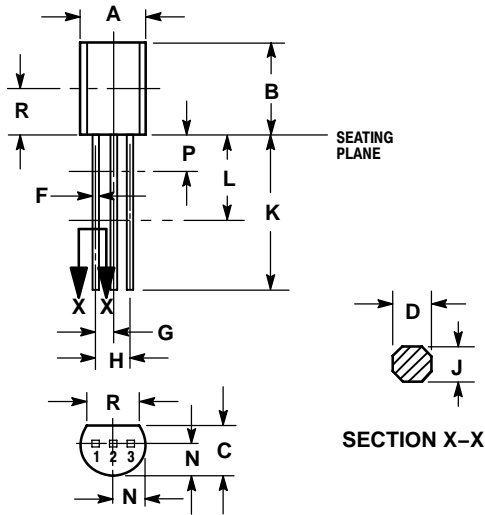


Figure 7. Capacitance

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## PACKAGE DIMENSIONS

TO-92 (TO-226)  
CASE 29-10  
ISSUE AL



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSIONS D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.44	5.21
B	0.290	0.310	7.37	7.87
C	0.125	0.165	3.18	4.19
D	0.018	0.021	0.457	0.533
F	0.016	0.019	0.407	0.482
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.135	---	3.43	---

### STYLE 1:

- PIN 1. EMITTER
- BASE
- COLLECTOR

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